

RJH1CD6DPQ-A0

1200 V - 20 A - IGBT Application: Inverter

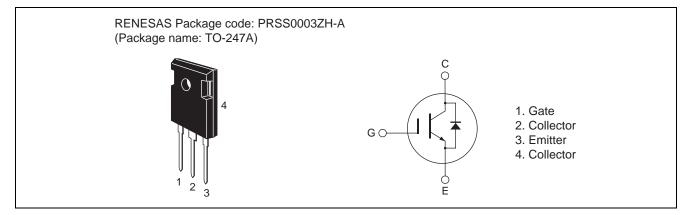
R07DS0452EJ0100 Rev.1.00 Jul 22, 2011

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 2.2 \text{ V typ.}$ (at $I_C = 20 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built in fast recovery diode ($t_{rr} = 100$ ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 100 \text{ ns typ.}$ (at $V_{CC} = 600 \text{ V}$, $V_{GE} = 15 \text{ V}$, $I_C = 20 \text{ A}$, $Rg = 5 \Omega$, $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

| | | | | $(Ta = 25^{\circ}C)$ |
|--|------------|-----------------------------------|-------------|----------------------|
| Item | | Symbol | Ratings | Unit |
| Collector to emitter voltage / diode reverse voltage | | V _{CES} / V _R | 1200 | V |
| Gate to emitter voltage | | V _{GES} | ±30 | V |
| Collector current | Tc = 25°C | Ι _C | 40 | А |
| | Tc = 100°C | Ιc | 20 | А |
| Collector peak current | | ic(peak) ^{Note1} | 80 | А |
| Collector to emitter diode forward current | | I _{DF} | 20 | А |
| Collector to emitter diode forward peak current | | i _{DF} (peak) Note1 | 80 | А |
| Collector dissipation | | Pc ^{Note2} | 297.6 | W |
| Junction to case thermal resistance (IGBT) | | θj-c ^{Note2} | 0.42 | °C/W |
| Junction temperature | | Tj | 150 | °C |
| Storage temperature | | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

2. Value at Tc = 25°C



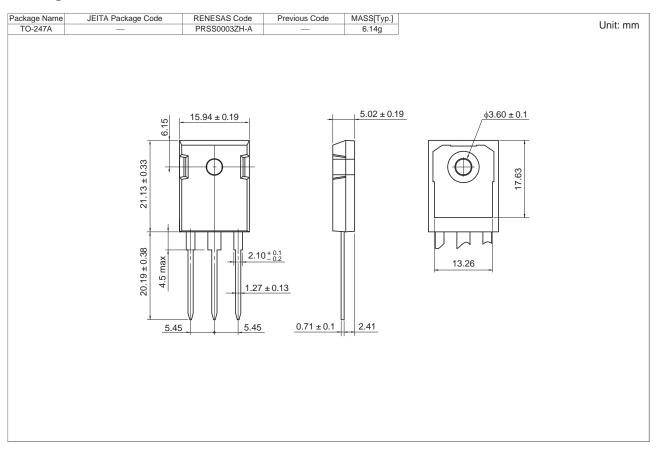
Electrical Characteristics

| | | | | | | $(Ta = 25^{\circ}C)$ | |
|--|----------------------------------|-----|------|-----|------|--|--|
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions | |
| Zero gate voltage collector current / Diode reverse current | I _{CES} /I _R | — | — | 5 | μA | $V_{CE} = 1200 \text{ V}, \text{ V}_{GE} = 0$ | |
| Gate to emitter leak current | I _{GES} | — | — | ±1 | μΑ | $V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$ | |
| Gate to emitter cutoff voltage | V _{GE(off)} | 4 | — | 8 | V | V _{CE} = 10 V, I _C = 1 mA | |
| Collector to emitter saturation voltage | V _{CE(sat)} | _ | 2.2 | _ | V | $I_{C} = 20 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$ | |
| Input capacitance | Cies | _ | 1600 | _ | pF | V _{CE} = 25 V | |
| Output capacitance | Coes | _ | 60 | _ | pF | $V_{GE} = 0$ | |
| Reveres transfer capacitance | Cres | | 35 | _ | pF | f = 1 MHz | |
| Switching time | t _{d(on)} | _ | 45 | _ | ns | $V_{CC} = 600 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$ | |
| | tr | _ | 15 | _ | ns | $I_{C} = 20 A$ $Rg = 5 \Omega$ Inductive load | |
| | t _{d(off)} | | 100 | _ | ns | | |
| | t _f | | 100 | _ | ns | | |
| Short circuit withstand time | t _{sc} | — | 5 | — | μs | $\label{eq:Vcc} \begin{array}{l} V_{CC} \leq 720 \mbox{ V}, \mbox{ V}_{GE} = 15 \mbox{ V} \\ Tc \leq 125^{\circ}C \end{array}$ | |
| | • | • | • | • | • | | |
| FRD forward voltage | V _F | _ | 1.7 | _ | V | $I_F = 20 A^{Note3}$ | |
| FRD reverse recovery time | t _{rr} | — | 100 | — | ns | I _F = 20 A di _F /dt = 100 A/μs | |

Notes: 3. Pulse test.



Package Dimension



Ordering Information

| Orderable Part Number | Quantity | Shipping Container |
|-----------------------|----------|--------------------|
| RJH1CD6DPQ-A0-T0 | 240 pcs | Box (Tube) |



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